

### GBJ30005 - GBJ3010/G

**Mechanical Data** 

Single Phase 30Amp Glass passivated Bridge Rectifiers

#### **Features**

- · Glass passivated die construction
- · Low forward voltage drop
- · High current capability
- · High surge current capability
- Plastic material-UL flammability 94V-0
- The G suffix is uses for photoresist chip, otherwise it is a knife scraping chip

#### **MECHANICAL DATA**

· Case: Molded plastic, GBJ

• Terminals: Plated Leads Solderable perMIL-STD-202, Method 208

· Polarity: As Marked on Case

Mounting Position: AnyMarking: Type Number

· Lead Free: For RoHS / Lead Free Version

# 1.Output Anode(+) GBJ 2.Input pin(~) 3.Input pin(~) 4.Output Cathode(-)

#### Maximum Ratings And Electrical Characteristics (@T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	GBJ	GBJ	GBJ	GBJ	GBJ	GBJ	GBJ	Unit
- Jiii 51		30005	3001	3002	3004	3006	3008	3010	
$V_{RRM}$	repetitive peak reverse voltage	50	100	200	400	600	800	1000	
$V_{RWM}$	Working Peak Reverse Voltage	50	100	200	400	600	800	1000	V
V <sub>RMS</sub>	RMS voltage	35 70 140 280 420 560 7		700	V				
$V_{DC}$	DC blocking voltage	50	100	200	400	600	800	1000	
IF <sub>AV</sub>	Average Rectified Output	30.0						А	
	Current (Note 1)@T <sub>C</sub> =90°C								
I <sub>FSM</sub>	Peak forward surge current, 8.3ms single	350						Α	
	half sine-wave								
I <sub>t</sub> <sup>2</sup>	I <sub>t</sub> <sup>2</sup> Rating for fusing (t<8.3ms)	508.375			A <sub>S</sub> <sup>2</sup>				
$V_{FM}$	Forward Voltage element @IF=15A	1.05				V			
I <sub>R</sub>	Peak Reverse Current@T <sub>A</sub> =25°C	5.0						uA	
	at rated DC blocking voltage @T <sub>A</sub> =125°C	500							
CJ	Typical junction capacitance	75			pF				
R <sub>θJA</sub>	Between junction and ambient, Without heatsink	22				°C/W			
R <sub>θJC</sub>	Between junction and case, With heatsink	8.0							
T <sub>J</sub>	Operation Temperature Range	-55 to +150					°C		
T <sub>STG</sub>	Storage Temperature Range	-55 to +150							

Note:(1)Thermal resistance from junction to case per element. Unit mounted on 75x75x1.6mm aluminum plate heat sink.

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#### **Ratings And Characteristic Curves**

Figure 1: Output Current Derating Curve

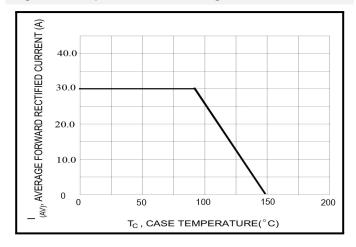


Figure 2: Typical Forward Characteristics (per leg)

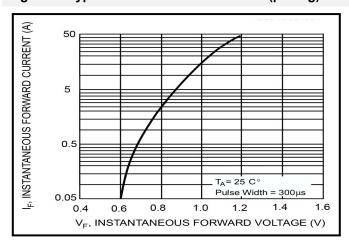
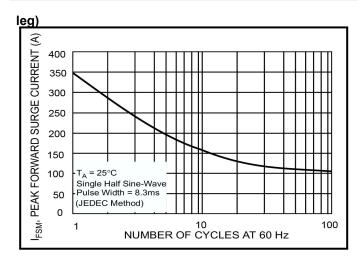


Figure 3:Maximum Peak Forward Surge Current (per



**Figure 4:Typical Junction Capacitance** 

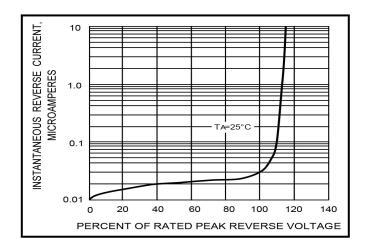
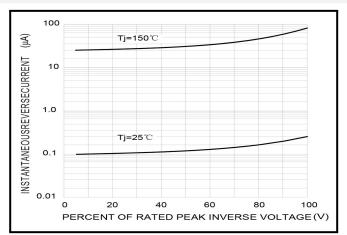


Figure 5:TYPICAL REVERSE CHARACTERISTICS



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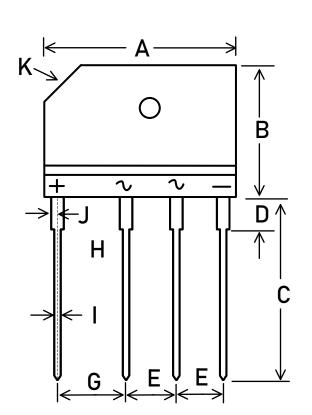


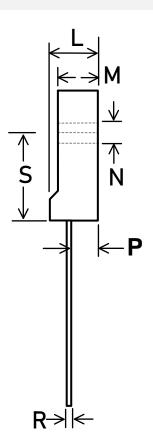


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## **Outline Drawing -GBJ**





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SYMBOL	MILLIMETER							
STWIDOL	MIN.	MAX.						
Α	29.70	30.3						
В	19.70	20.3						
С	17.00	18.00						
D	3.80	4.20						
Е	7.30	7.70						
G	9.80	10.20						
Н	2.00	2.40						
I	0.90	1.10						
J	2.30	2.70						
K	3.0x45°							
L	4.40	4.80						
М	3.40	3.80						
N	3.10	3.40						
Р	2.50	2.90						
R	0.60	0.80						
S	10.80	11.20						